

## Performance of Arrays of SIS Junctions in Heterodyne Mixers

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*D.-G. Crete, W.R. McGrath, P.L. Richards and F.L. Lloyd. "Performance of Arrays of SIS Junctions in Heterodyne Mixers." 1987 Transactions on Microwave Theory and Techniques 35.4 (Apr. 1987 [T-MTT]): 435-440.*

We have made a systematic experimental study of the performance of millimeter-wave quasiparticle heterodyne mixers which use arrays of SIS tunnel junctions. Sets of arrays with  $N = 1, 5, 10, 25$ , and  $50$  junctions in series were fabricated by photolithography. All of the arrays in a given set were made on a single silicon wafer so that their response time parameter  $\omega_{S/R/N/C}$  would be the same. Junction areas were scaled so that the total impedance was the same for each array in a set. Sets of arrays from four wafers with values of  $\omega_{S/R/N/C}$  ranging from  $2.6$  to  $13$  were evaluated in mixers at  $33$  and  $36$  GHz. These measurements showed that the signal power required to saturate the mixers varies as  $N^2$  and that the conversion efficiency is nearly independent of  $N$  for all values of  $\omega_{S/R/N/C}$ . The mixer noise temperature is independent of  $N$  for large values of  $\omega_{S/R/N/C}$ . Therefore, the dynamic range of an SIS quasiparticle mixer can increase in proportion to  $N^2$ . For small values of  $\omega_{S/R/N/C}$ , however, the mixer noise increases systematically with  $N$ . This correlation suggests that the junction capacitance affects the coupling between junctions that can contribute to the noise.

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